

CT2 Front End IC

Description

U7001BG is a monolithic GaAs transmit/ receive front end with power amplifier, low noise amplifier and antenna switch. It is specially designed for operation in CT2 band and suitable for a frequency range of 839 MHz to 952 MHz with external matching.

Electrostatic sensitive device.

Observe precautions for handling.



Features

- Low supply voltage 3.6 V typical (min. 2.7 V)
- High power added efficiency (typ. 40%)
- Low power consumption in receive mode
- Power down control pin for low noise amplifier
- Gain control of power amplifier
- Low noise amplifier
- Optional high output power 50 mW @ 5 V supply voltage

Benefits

- Extended talk time due to low power consumption and high PAE
- Few external components and very small package save space

Block Diagram

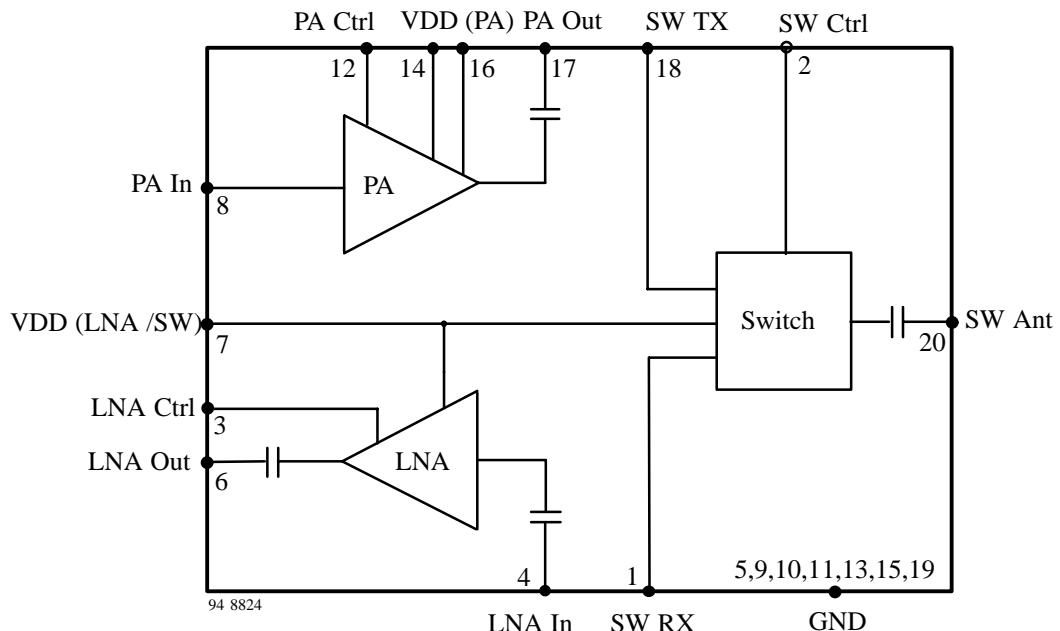


Figure 1. Block diagram

Ordering Information

Extended Type Number	Package	Remarks
U7001BG-BFS	SSO20	Tube
U7001BG-BFSG3	SSO20	Taped and reeled

U7001BG

Pin Description

The pinning diagram shows the layout of the 20 pins in a SSO20 package. Pins 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 18, 19, and 20 are labeled along the left side. Pin 1 is SW RX, Pin 2 is SW Ctrl, Pin 3 is LNA Ctrl, Pin 4 is LNA In, Pin 5 is GND, Pin 6 is LNA Out, Pin 7 is VDD (LNA/SW), Pin 8 is PA In, Pin 9 is GND, Pin 10 is GND, Pin 11 is GND, Pin 12 is PA Ctrl, Pin 13 is GND, Pin 14 is VDD1 (PA), Pin 15 is GND, Pin 16 is VDD2 (PA), Pin 17 is PA Out, Pin 18 is SW TX, Pin 19 is GND, and Pin 20 is SW Ant.

Pin	Symbol	Function
1	SW RX	Switch RX output
2	SW Ctrl	Switch control input
3	LNA Ctrl	LNA control input
4	LNA In	Low noise amplifier input
5	GND	Ground
6	LNA Out	LNA output
7	VDD (LNA/SW)	LNA & Switch power supply voltage
8	PA In	Power amplifier input
12	PA Ctrl	PA control input
14	VDD1(PA)	PA power supply voltage 1
16	VDD2(PA)	PA power supply voltage 2
17	PA Out	PA output
18	SW TX	Switch TX input
20	SW Ant	Switch antenna output

Figure 2. Pinning SSO20

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltages	V_{DD}	+ 7	V
Input voltages	V_i	0 to VDD	V
Control voltages	V_C	0 to VDD	V
Channel temperature	T_{ch}	125	°C
Storage-temperature range	T_{stg}	- 40 to + 125	°C

Thermal Resistance

Parameters	Symbol	Value	Unit
Channel ambient	R_{thch}	140	K/W

Operating Range

Parameters	Symbol	Value	Unit
Supply voltages	V_{DD}	2.7 to 5.25	V
Ambient-temperature range	T_{amb}	- 40 to + 85	°C

Electrical Characteristics Low Noise Amplifier (LNA)

Test conditions (unless otherwise specified): $V_{DD} = 3.3$ V, $T_{amb} = 25^\circ\text{C}$, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$, $f_{RF} = 866$ MHz

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pin 7	V_{DD}	2.9	3.6	5.25	V
Supply current	@ $V_{DD} = 2.9$ V, Pin 7	I_S		3.5	5.0	mA
Supply current	@ $V_{DD} = 2.9$ V, Pin 7 LNA Ctrl = 0 V: LNA "off"	I_S		0.5		mA
Frequency range	Pin 4	f	839	866	952	MHz
Linear power gain	Pins 4 and 6	G_p		14		dB
Noise figure	Pins 4 and 6	NF		2.0	2.5	dB
Compression	Pins 4 and 6	P_{-1dB}	-29	-27		dBm
Third-order input intercept point	Pins 4 and 6	$IIP3$	-19	-17		dBm
Isolation	Pins 6 and 4 (from output to input)	$Isol_{LNA}$	20	25		dB
Input impedance	Pin 4			50		Ω
Output impedance	Pin 6		50	100		Ω
LNA control voltage	LNA Mode "off" LNA Mode "on"	Pin 3 $V_{LNA\ Ctrl}$	$V_{DD}-0.5$	0.0 V_{DD}	0.5	V V

Test conditions (unless otherwise specified); $V_{DD} = 2.9$ V, $T_{amb} = 25^\circ\text{C}$, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$; $f_{RF} = 866$ MHz

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pin 7	V_{DD}	2.9	3.6	5.25	V
Supply current	@ $V_{DD} = 2.7$ V, Pin 7	I_S		3.0	4.0	mA
Supply current	@ $V_{DD} = 2.7$ V, Pin 7 LNA Ctrl = 0 V: LNA "off"	I_S		0.5		mA
Frequency range	Pin 4	f	839	866	952	MHz
Linear power gain	Pins 4 and 6	G_p		12		dB
Noise figure	Pins 4 and 6	NF		2.0	2.5	dB
Compression	Pins 4 and 6	P_{-1dB}	-29	-28		dBm
Third-order input intercept point	Pins 4 and 6	$IIP3$	-19	-18		dBm
Isolation	Pins 6 and 4 (from output to input)	$Isol_{LNA}$	20	25		dB
Input impedance	Pin 4			50		Ω
Output impedance	Pin 6		50	100		Ω
LNA control voltage	LNA Mode "off" LNA Mode "on"	Pin 3 $V_{LNA\ Ctrl}$	$V_{DD}-0.5$	0.0 V_{DD}	0.5	V V

U7001BG

Electrical Characteristics Power Amplifier

Test conditions (unless otherwise specified); $V_{DD} = 5.0$ V, PA Ctrl = 5 V, Tamb = 25°C, referred to test circuit.
 System Impedance $Z_0 = 50 \Omega$; $f_{RF} = 866$ MHz

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pins 14 and 16	$V_{DD1,2}$	2.7	3.6	5.25	V
Supply current	Pins 14 and 16	I_S		33	40	mA
Supply current	Pin 12	I_{Ctrl}		5.0	6.0	mA
Frequency range	Pin 8	f	839	866	952	MHz
Linear power gain	Pins 8 and 17	G_p	34	36		dB
Power response	@ $P_{in} = -14$ dBm					
Output power	At 3 dB gain compression; Pin 17	P_{out}	17	18		dBm
Gain control range	Pins 17 and 12	G_c	30	33		dB
Gain control voltage	$P_{out} = P_{out_{max}}$	$V_{PA\ Ctrl}$		4.5	V_{DD}	V
Gain control voltage	$P_{out} = P_{out_{max}} - 16$ dB	$V_{PA\ Ctrl}$		1.2		V
Gain control voltage	$P_{out} = P_{out_{min}}$	$V_{PA\ Ctrl}$		0.0		V
Switching time	Pins 12 and 17					
Turn-on time	90% $P_{out_{max}}$	t_{on}		2		μs
Turn-off time	10% $P_{out_{max}}$	t_{off}		5		μs
Harmonic levels	At 3 dB gain compression		-18	-25		dBc
Isolation	Pins 17 and 8 (from output to input)	$Isol_{PA}$	42	45		dB
Input matching	Pin 8	$VSWR_{in}$	1.9 : 1	1.6 : 1		
Output matching	Pin 17	$VSWR_{out}$		2.0 : 1		
Power added efficiency	Pin 17	η_{PAE}		40		%
Input impedance	Pin 8	Z_{in}		50		Ω
Output impedance	Pin 17	Z_{out}		50		Ω

Electrical Characteristics Power Amplifier

Test conditions (unless otherwise specified); $V_{DD} = 3.6$ V, PA Ctrl = 3.6 V, Tamb = 25°C, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$; $f_{RF} = 866$ MHz

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pins 14 and 16	$V_{DD1,2}$	2.7	3.6	5.25	V
Supply current	Pins 14 and 16	I_S		30	36	mA
Supply current	Pin 12	I_{Ctrl}		5.0	6.0	mA
Frequency range	Pin 8	f	839	866	952	MHz
Linear power gain	Pins 8 and 17	G_p	32	35		dB
Power response	@ $P_{in} = -14$ dBm					
Output power	At 3 dB gain compression; Pin 17	P_{out}	15	17		dBm
Gain control range	Pins 17 and 12	G_c	30	33		dB
Gain control voltage	$P_{out} = P_{out,max}$	$V_{PA\ Ctrl}$		2.9	V_{DD}	V
Gain control voltage	$P_{out} = P_{out,max} - 16$ dB	$V_{PA\ Ctrl}$		1.2		V
Gain control voltage	$P_{out} = P_{out,min}$	$V_{PA\ Ctrl}$		0.0		V
Switching time	Pins 12 and 17					
Turn-on time	90% $P_{out,max}$	t_{on}		2		μs
Turn-off time	10% $P_{out,max}$	t_{off}		5		μs
Harmonic levels	At 3 dB gain compression		-18	-25		dBc
Isolation	Pins 17 and 8 (from output to input)	$Isol_{PA}$	42	45		dB
Input matching	Pin 8	$VSWR_{in}$	1.9 : 1	1.6 : 1		
Output matching	Pin 17	$VSWR_{out}$		2.0 : 1		
Power added efficiency	Pin 17	η_{PAE}		45		%
Input impedance	Pin 8	Z_{in}		50		Ω
Output impedance	Pin 17	Z_{out}		50		Ω

Electrical Characteristics Power Amplifier

Test conditions (unless otherwise specified); $V_{DD} = 2.7 \text{ V}$, PA Ctrl = 2.7 V, $T_{amb} = 25^\circ\text{C}$, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$; $f_{RF} = 866 \text{ MHz}$

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pins 14 and 16	$V_{DD1,2}$	2.7	3.6	5.25	V
Supply current	Pins 14 and 16	I_S		25	30	mA
Supply current	Pin 12	I_{Ctrl}		4.5	5.5	mA
Frequency range	Pin 8	f	839	866	952	MHz
Linear power gain	Pins 8 and 17	G_p	30	32		dB
Power response	@ $P_{in} = -15 \text{ dBm}$					
Output power	At 3 dB gain compression; Pin 17	P_{out}	12	14		dBm
Gain control range	Pins 17 and 12	G_c	30	33		dB
Gain control voltage	$P_{out} = P_{out_{max}}$	$V_{PA \text{ Ctrl}}$		2.7	V_{DD}	V
Gain control voltage	$P_{out} = P_{out_{max}} - 16 \text{ dB}$	$V_{PA \text{ Ctrl}}$		1.5		V
Gain control voltage	$P_{out} = P_{out_{min}}$	$V_{PA \text{ Ctrl}}$		0.0		V
Switching time	Pins 12 and 17					
Turn-on time	90% $P_{out_{max}}$	t_{on}		2		μs
Turn-off time	10% $P_{out_{max}}$	t_{off}		5		μs
Harmonic levels	At 3 dB gain compression		- 20	- 25		dBc
Isolation	Pins 16 and 8 (from output to input)	$Isol_{PA}$	42	45		dB
Input matching	Pin 8	$VSWR_{in}$	1.9 : 1	1.4 : 1		
Output matching	Pin 16	$VSWR_{out}$		2.0 : 1		
Power added efficiency	Pin 16	η_{PAE}		35		%
Input impedance	Pin 8	Z_{in}		50		Ω
Output impedance	Pin 16	Z_{out}		50		Ω

Electrical Characteristics Antenna Switch

Test conditions (unless otherwise specified); $V_{DD} = 3.6$ V, Tamb = 25°C, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$; f_{RF} = 866 MHz

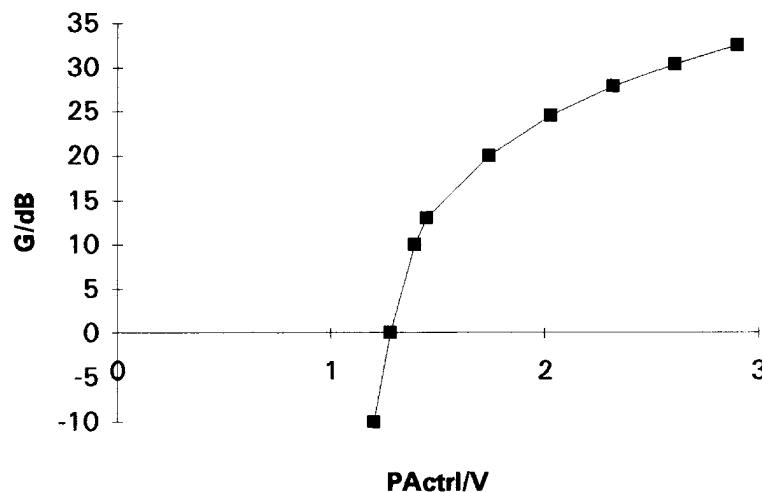
Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage range	Pin 7	V_{DD}	2.7	3.6	5.0	V
Frequency range	Pins 1, 18 and 20	f	839	866	952	MHz
Insertion loss	@ P _{in} = +16 dBm; Pin 18 to Pin 20; “TX Mode”	IL _{TX}		1.0	1.3	dB
Isolation	@ P _{in} = +16 dBm; Pin 18 to Pin 1; “TX Mode”	Isol _{TX}	12	15		dB
Insertion loss	@ P _{in} = -26 dBm; Pin 20 to Pin 1; “RX Mode”	IL _{RX}		1.0	1.3	dB
Isolation	@ P _{in} = -26 dBm; Pin 20 to Pin 18; “RX Mode”	Isol _{TX}	16	18		dB
Switch control	RX Mode; Pin 2	$V_{SW\ Ctrl}$	0	0	0.05	V
	TX Mode	$V_{SW\ Ctrl}$	$V_{DD} - 0.5$	V_{DD}	$V_{DD} + 0.5$	V
Input impedance	TX Mode; Pin 18	Z_{in}		50		Ω
Input impedance	RX Mode; Pin 1	Z_{in}		50		Ω
Output impedance	RX TX-Mode; Pin 20	Z_{out}		50		Ω

Test conditions (unless otherwise specified); $V_{DD} = 2.7$ V, Tamb = 25°C, referred to test circuit.
 System impedance $Z_0 = 50 \Omega$; f_{RF} = 866 MHz

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply-voltage range	Pin 7	V_{DD}	2.7	3.6	5.0	V
Frequency range	Pins 1, 18 and 20	f	839	866	952	MHz
Insertion loss	@ P _{in} = +14 dBm; Pin 18 to Pin 20; “TX Mode”	IL _{TX}		1.0	1.3	dB
Isolation	@ P _{in} = +14 dBm; Pin 18 to Pin 1; “TX Mode”	Isol _{TX}	11	13		dB
Insertion loss	@ P _{in} = -26 dBm; Pin 20 to Pin 1; “RX Mode”	IL _{RX}		1.0	1.3	dB
Isolation	@ P _{in} = -26 dBm; Pin 20 to Pin 18; “RX-Mode”	Isol _{TX}	15			dB
Switch control	RX Mode; Pin 2	$V_{SW\ Ctrl}$	0	0	0.05	V
	TX Mode; Pin 2	$V_{SW\ Ctrl}$	$V_{DD} - 0.5$	V_{DD}	$V_{DD} + 0.5$	V
Input impedance	TX Mode; Pin 18	Z_{in}		50		Ω

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Input impedance	RX Mode; Pin 1	Z_{in}		50		Ω
Output impedance	RX TX-Mode; Pin 20	Z_{out}		50		Ω

Gain Variation with Vctrl



94 8838

Figure 3. Gain variation of power amplifier with switch and filter. @ $V_{DD} = 3.6$ V (typical values)

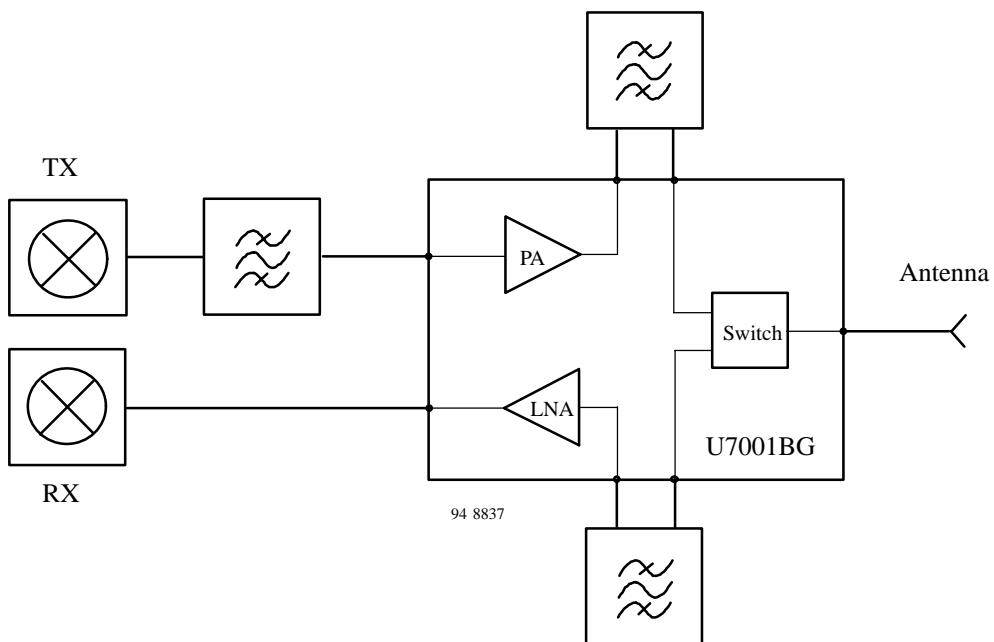


Figure 4. Application 1

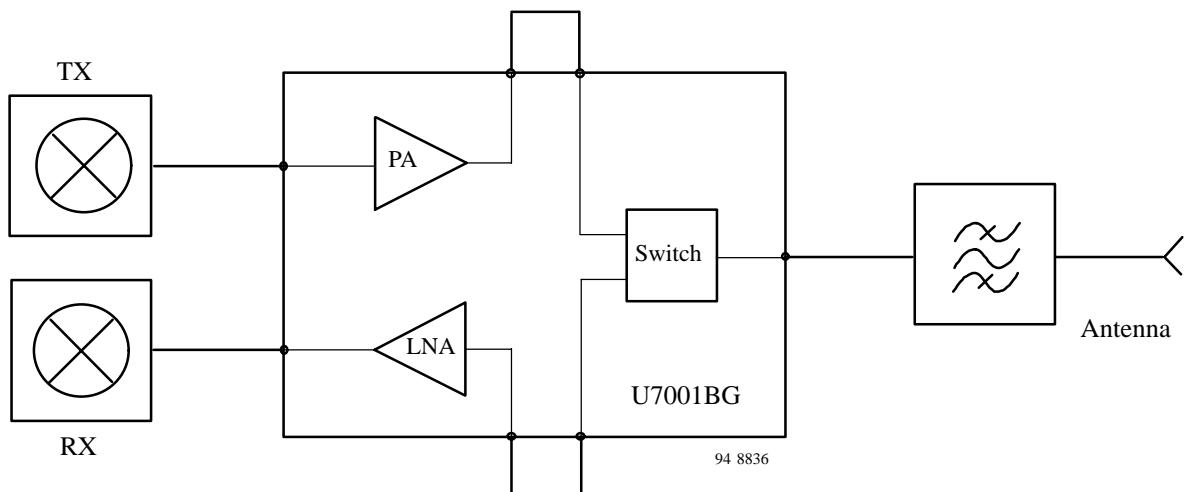


Figure 5. Application 2

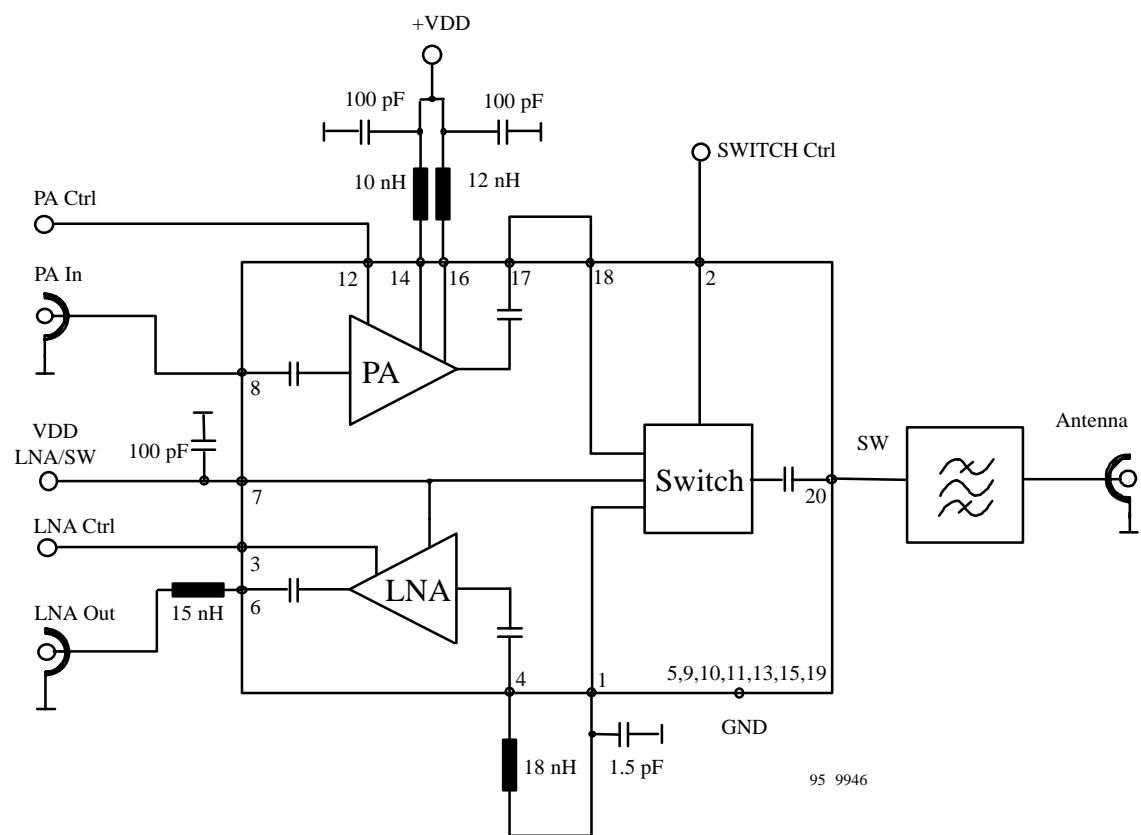
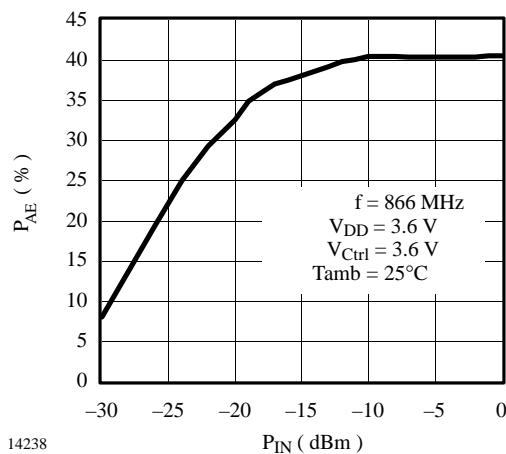
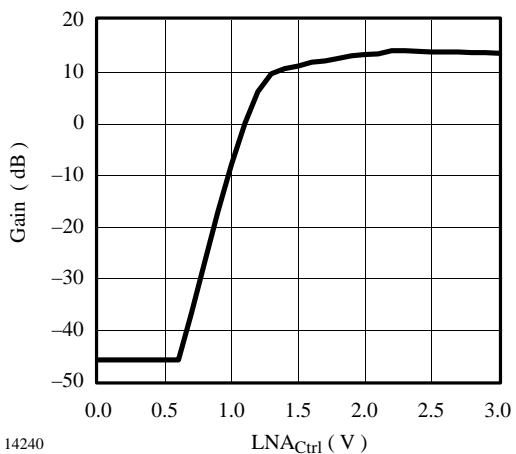


Figure 6. Application for minimal component count



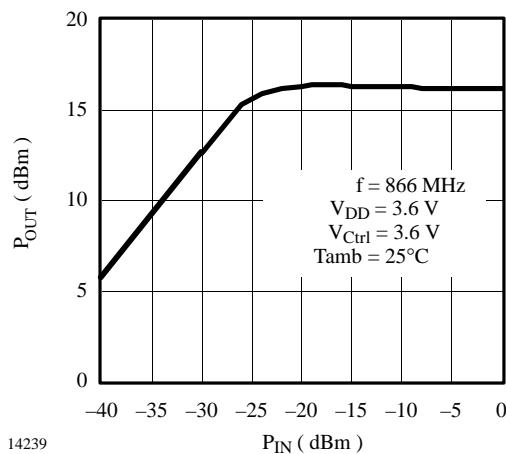
14238

Figure 7. PAE versus PIN

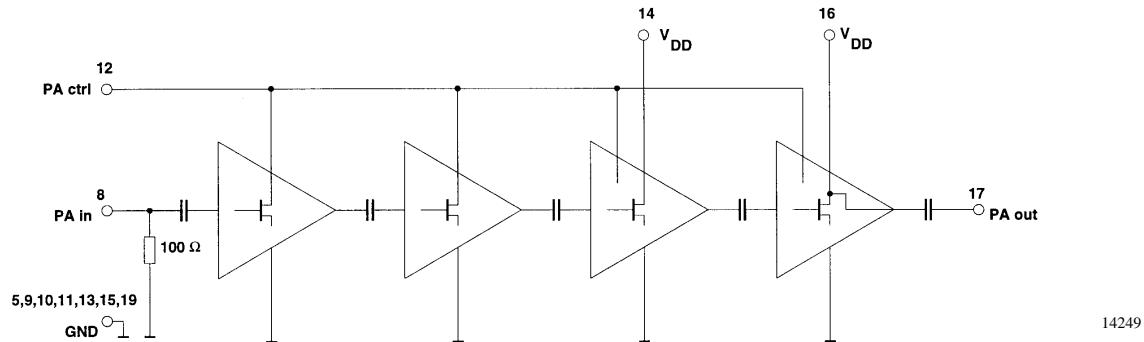


14240

Figure 9. LNA gain versus control voltage



14239

Figure 8. P_{OUT} versus PIN

14249

Figure 10. Power amplifier – circuit topology

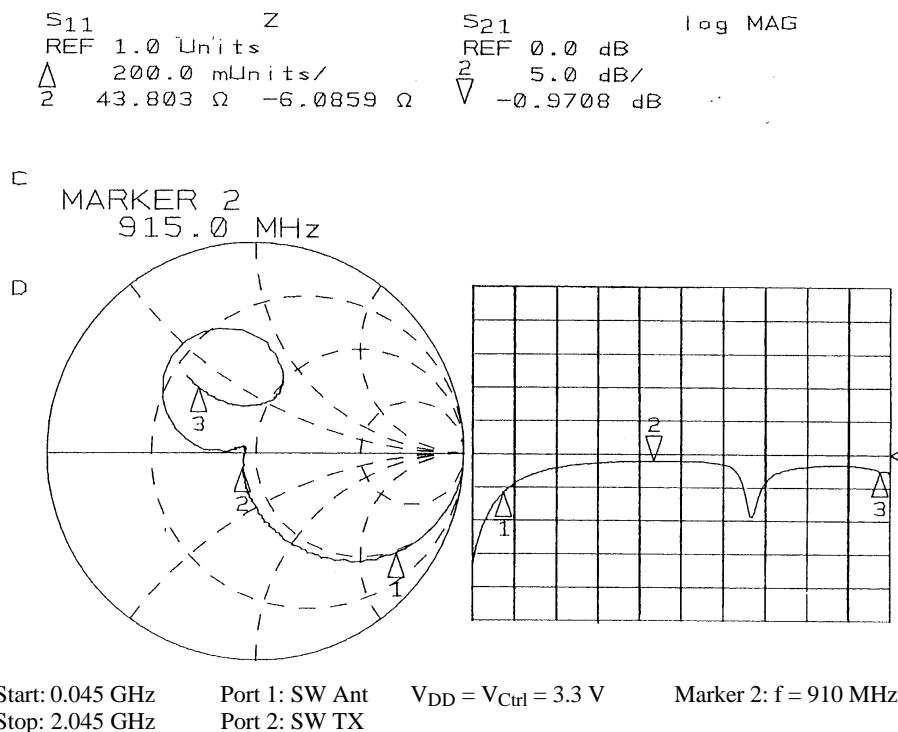


Figure 11. Switch TX insertion loss

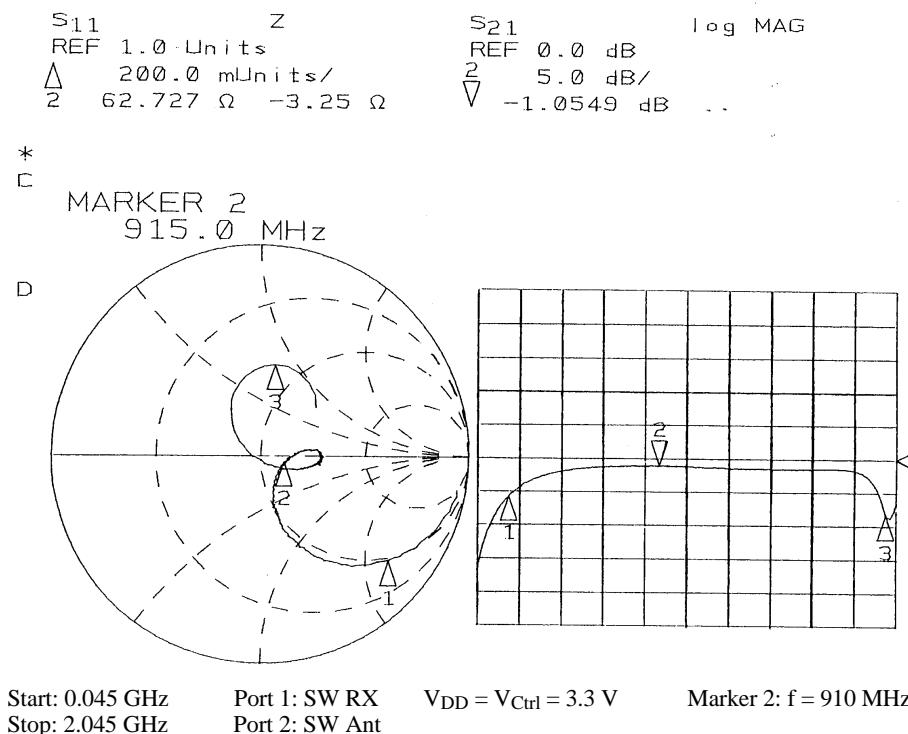
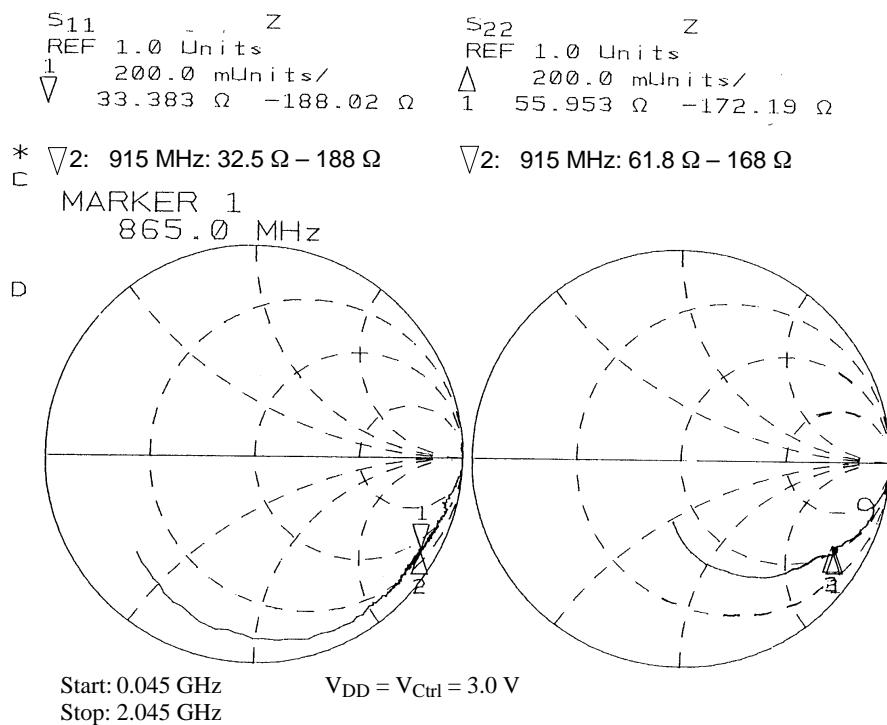
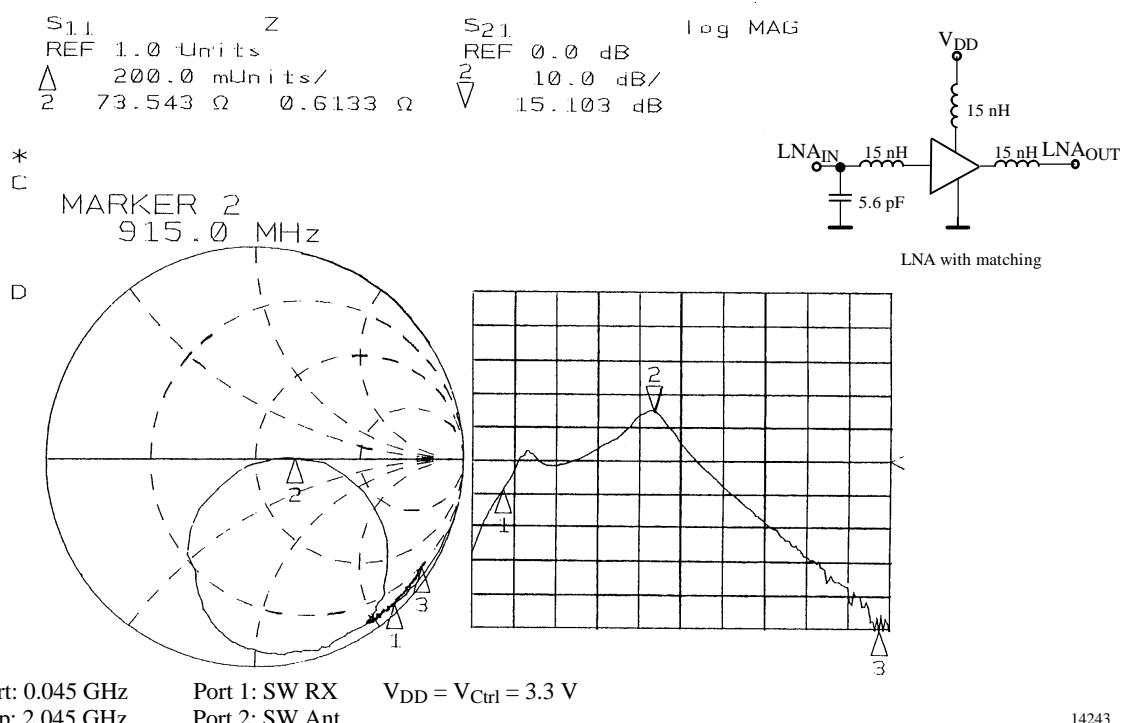


Figure 12. Switch RX insertion loss



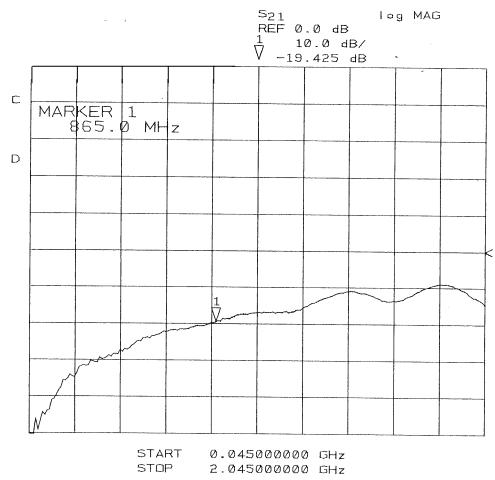
14244

Figure 13. LNA without matching



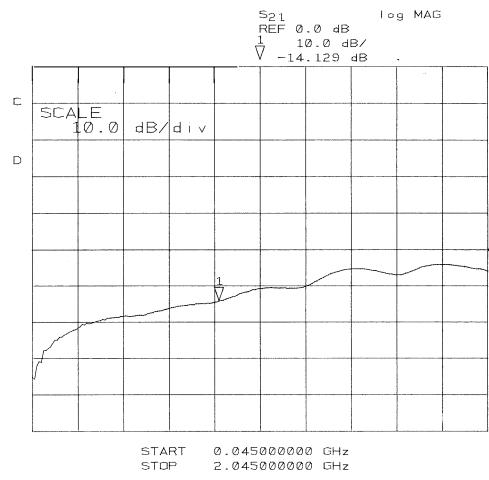
14243

Figure 14. LNA with external matching



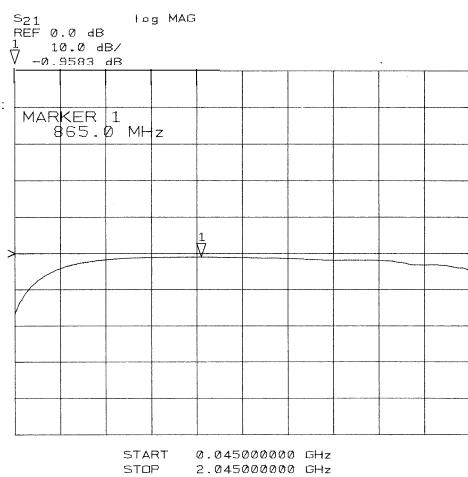
14245

Figure 15. Switch Ant – TX isolation
 $V_{DD} = 3.0$ V, $V_{Ctrl} = 0$ V

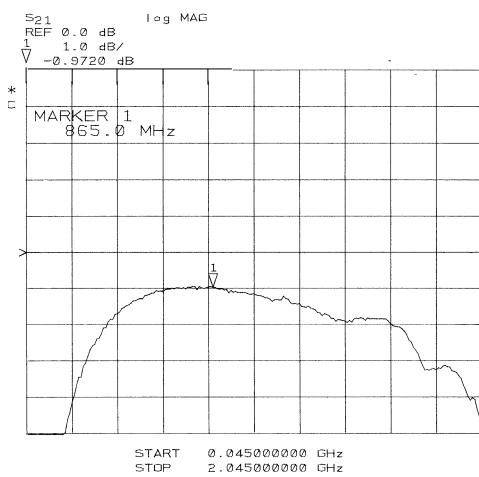


14246

Figure 16. Switch Ant – RX isolation
 $V_{DD} = 3.0$ V, $V_{Ctrl} = 3.0$ V



SW RX – Ant insertion loss

 $V_{DD} = 3.0$ V $V_{Ctrl} = 0$ V

14247

Figure 17. Matched on both sides

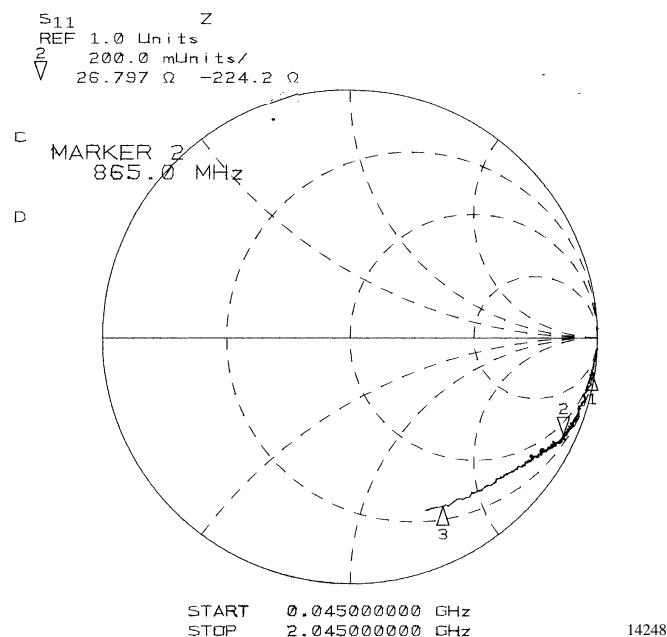
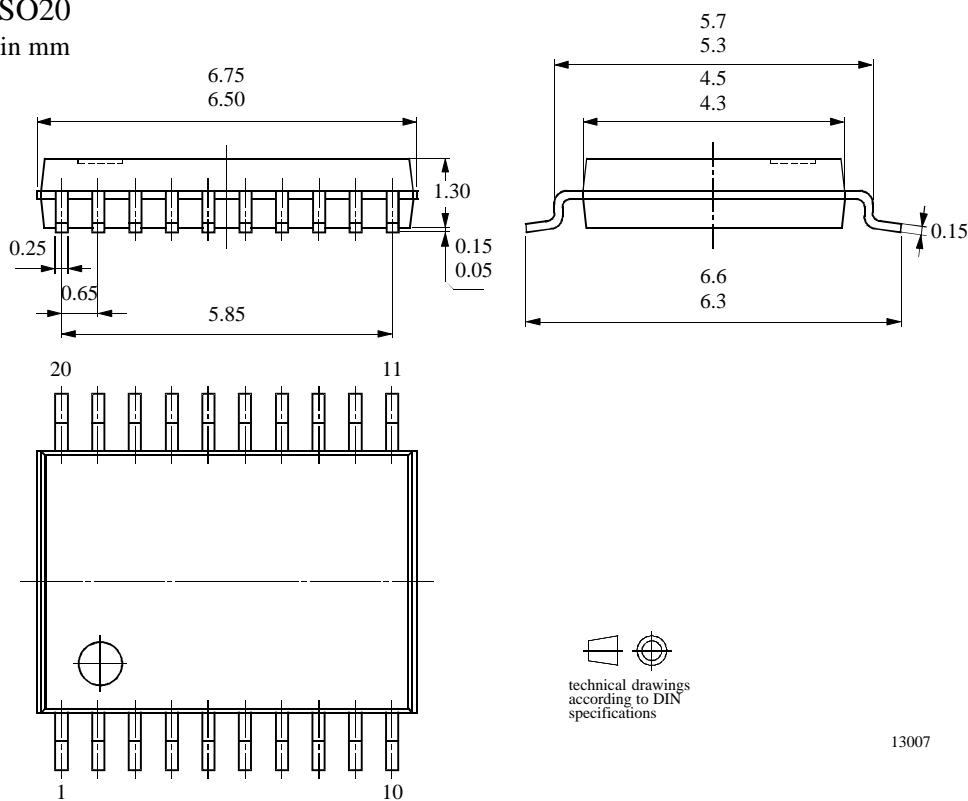


Figure 18. LNA switched off, $V_{DD} = 3.0$ V

Package Information

Package SSO20

Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Atmel Germany GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Atmel Germany GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Atmel Germany GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Atmel Wireless & Microcontrollers products for any unintended or unauthorized application, the buyer shall indemnify Atmel Wireless & Microcontrollers against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Data sheets can also be retrieved from the Internet: <http://www.atmel-wm.com>

Atmel Germany GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2594, Fax number: 49 (0)7131 67 2423